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# 2N3700 • 2N3701

## NPN SMALL SIGNAL GENERAL PURPOSE AMPLIFIERS

- $V_{CEO} \dots 80 \text{ V (MIN) @ } 30 \text{ mA}$
- $V_{CE(sat)} \dots 0.5 \text{ V (MAX) @ } 500 \text{ mA}$

### ABSOLUTE MAXIMUM RATINGS

#### Maximum Temperatures

- Storage Temperature
- Operating Junction Temperature
- Lead Temperature (60 seconds)

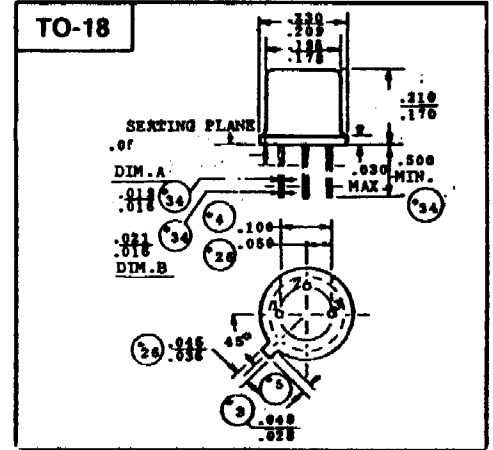
#### Maximum Power Dissipation

- Total Dissipation at 25°C Case Temperature **1.8 W**
- at 100°C Case Temperature **1.0 W**
- at 25°C Ambient Temperature **0.5 W**

#### Maximum Voltages and Current

- $V_{CBO}$  Collector to Base Voltage **140 V**
- $V_{CEO}$  Collector to Emitter Voltage **80 V**
- $V_{EBO}$  Emitter to Base Voltage **70 V**
- $I_C$  Collector Current **1.0 A**

-85°C to +200°C  
 200°C  
 300°C



### ELECTRICAL CHARACTERISTICS (25°C Ambient Temperature unless otherwise noted)

SYMBOL	CHARACTERISTIC	2N3700		2N3701		UNITS	TEST CONDITIONS
		MIN.	MAX.	MIN.	MAX.		
$h_{FE}$	DC Pulse Current Gain (Note 5)	100	300	40	120		$I_C = 150 \text{ mA}, V_{CE} = 10 \text{ V}$
		90		40	120		$I_C = 10 \text{ mA}, V_{CE} = 10 \text{ V}$
		50		30	100		$I_C = 0.1 \text{ mA}, V_{CE} = 10 \text{ V}$
		50		30	100		$I_C = 500 \text{ mA}, V_{CE} = 10 \text{ V}$
		15		15			$I_C = 1.0 \text{ A}, V_{CE} = 10 \text{ V}$
		40					$I_C = 150 \text{ mA}, V_{CE} = 10 \text{ V}, T_A = -55^\circ\text{C}$
$V_{BE(sat)}$	Pulsed Base Saturation Voltage		1.1		1.1	V	$I_C = 150 \text{ mA}, I_B = 15 \text{ mA}$
$V_{CE(sat)}$	Pulsed Collector Saturation Voltage (Note 5)		0.2		0.2	V	$I_C = 150 \text{ mA}, I_B = 15 \text{ mA}$
			0.5		0.5	V	$I_C = 500 \text{ mA}, I_B = 50 \text{ mA}$
$h_{fe}$	High Frequency Current Gain	5.0	10	4.0	10		$I_C = 50 \text{ mA}, V_{CE} = 10 \text{ V}, f = 20 \text{ MHz}$
$h_{fe}$	Small Signal Current Gain	80	400	30	200		$I_C = 1.0 \text{ mA}, V_{CE} = 5.0 \text{ V}, f = 1.0 \text{ kHz}$
$C_{ob}$	Output Capacitance		12		12	pF	$I_E = 0, V_{CB} = 10 \text{ V}, f = 1.0 \text{ MHz}$
$C_{ib}$	Input Capacitance		60		60	pF	$I_C = 0, V_{EB} = 0.5 \text{ V}, f = 1.0 \text{ MHz}$
$\tau_{b'Cc}$	Collector to Base Time Constant	25	400	25	400	ps	$I_C = 10 \text{ mA}, V_{CB} = 10 \text{ V}, f = 4.0 \text{ MHz}$
$I_{CBO}$	Collector Cutoff Current		10		10	nA	$I_E = 0, V_{CB} = 90 \text{ V}$
			10		10	$\mu\text{A}$	$I_E = 0, V_{CB} = 90 \text{ V}, T_A = 150^\circ\text{C}$
$I_{EBO}$	Emitter Cutoff Current		10		10	nA	$I_C = 0, V_{EB} = 5.0 \text{ V}$
$BV_{CBO}$	Collector to Base Breakdown Voltage	140		140		V	$I_C = 100 \mu\text{A}, I_E = 0$
$V_{CEO(sus)}$	Collector to Emitter Sustaining Voltage (Notes 4 & 5)	80		80		V	$I_C = 30 \text{ mA}, I_B = 0$
$BV_{EBO}$	Emitter to Base Breakdown Voltage	7.0		7.0		V	$I_C = 0, I_E = 100 \mu\text{A}$
NF	Noise Figure		4.0			dB	$I_C = 100 \mu\text{A}, V_{CE} = 10 \text{ V}, f = 1.0 \text{ kHz}, R_G = 1.0 \text{ k}\Omega$